



DMPH4013SK3Q

Product Summary

BV _{DSS}	Rds(on) max	Ι _D T _C = +25°C
-40V	$15m\Omega @ V_{GS} = -10V$	-55A
-40 V	23mΩ @ V _{GS} = -4.5V	-50A

Description

This MOSFET has been designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

- Reverse Polarity Protection
- Motor Control
- Power Management

Features and Benefits

- Rated to +175°C Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switch (UIS) Test in Production

175°C P-CHANNEL ENHANCEMENT MODE MOSFET

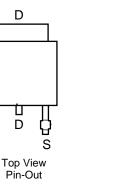
- Low On-Resistance
- Fast Switching Speed
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

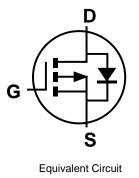
Mechanical Data

- Case: TO252 (DPAK)
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram
- Terminals: Finish Matte Tin Finish Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 3
- Weight: 0.33 grams (Approximate)



Top View





Ordering Information (Note 5)

	Part Number	Case	Packaging	
	DMPH4013SK3Q-13	TO252 (DPAK)	2,500/Tape & Reel	
Notes: 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.				

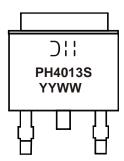
EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. Automotive products are AEC-Q101 qualified and are PPAP capable. Refer to https://www.diodes.com/quality/.

5. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



⊃!! = Manufacturer's Marking PH4013S = Product Type Marking Code YYWW = Date Code Marking YY = Year (ex: 18 = 2018) WW = Week (01 to 53)



Maximum Ratings (@ $T_A = +25^{\circ}C$, unless otherwise specified.)

Characteristic			Symbol	Value	Unit
Drain-Source Voltage	V _{DSS}	-40	V		
Gate-Source Voltage			V _{GSS}	±20	V
Continuous Drain Current (Note 7) V_{GS} = -10V	Steady State	T _C = +25°C T _C = +100°C	ID	-55 -40	A
Pulsed Drain Current (10μs Pulse, Duty Cycle = 1%)			I _{DM}	-120	A
Maximum Body Diode Forward Current (Note 7)			Is	-3.6	A
Pulsed Source Current (10µs Pulse, Duty Cycle = 1%)			I _{SM}	-120	A
Avalanche Current, L = 0.1mH (Note 8)			I _{AS}	-40	A
Avalanche Energy, L = 0.1mH (Note 8)			E _{AS}	69	mJ

Thermal Characteristics (@ T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 6)		PD	2.1	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	$R_{ extsf{ heta}JA}$	71	°C/W
Total Power Dissipation (Note 7)		PD	3.7	W
Thermal Resistance, Junction to Ambient (Note 7)	Steady State	$R_{ ext{ heta}JA}$	41	°C/W
Thermal Resistance, Junction to Case		$R_{ ext{ heta}JC}$	1.7	C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +175	°C

Electrical Characteristics (@ T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 9)						
Drain-Source Breakdown Voltage	BV _{DSS}	-40	—	—	V	$V_{GS} = 0V, I_D = -250\mu A$
Zero Gate Voltage Drain Current	IDSS		—	-1	μA	$V_{DS} = -40V, V_{GS} = 0V$
Gate-Source Leakage	IGSS	_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 9)	•				•	-
Gate Threshold Voltage	V _{GS(TH)}	-1.0	—	-3.0	V	$V_{DS} = V_{GS}$, $I_D = -250 \mu A$
Static Drain-Source On-Resistance	D		10	15	mΩ	$V_{GS} = -10V, I_D = -10A$
Static Drain-Source On-Resistance	R _{DS(ON)}		15	23	1115.2	$V_{GS} = -4.5V, I_D = -8A$
Diode Forward Voltage	V _{SD}	_	-0.7	-1.2	V	$V_{GS} = 0V, I_{S} = -1A$
DYNAMIC CHARACTERISTICS (Note 10)	•				•	-
Input Capacitance	Ciss	_	4004	_		$V_{DS} = -20V, V_{GS} = 0V$ f = 1MHz
Output Capacitance	Coss		309	—	pF	
Reverse Transfer Capacitance	Crss		229	—		
Gate Resistance	Rg		3.5	—	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$
Total Gate Charge (V _{GS} = -4.5V)	Qg		31	—		
Total Gate Charge (V _{GS} = -10V)	Qg		67	—	nC	V _{DS} = -20V, I _D = -10A
Gate-Source Charge	Q _{gs}	_	13.2	_	nc	
Gate-Drain Charge	Q _{gd}		11	—		
Turn-On Delay Time	t _{D(ON)}	_	9.9	_		
Turn-On Rise Time	t _R	_	32	_		$V_{GS} = -10V, V_{DD} = -20V,$ $R_G = 3\Omega, I_D = -10A$
Turn-Off Delay Time	t _{D(OFF)}		46		ns	
Turn-Off Fall Time	t _F		53			
Reverse Recovery Time	t _{RR}		19.5	_	ns	I _F = -10A, di/dt = -100A/µs
Reverse Recovery Charge	Q _{RR}	_	11.6	—	nC	I _F = -10A, di/dt = -100A/µs

Notes: 6. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.

7. Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.

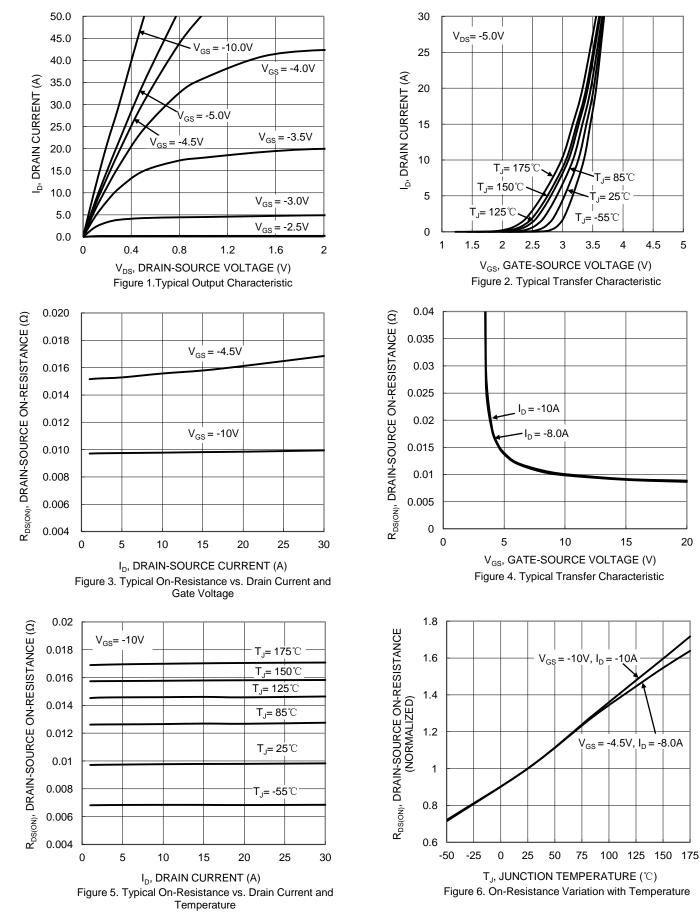
8. I_{AS} and E_{AS} ratings are based on low frequency and duty cycles to keep T_J = +25°C.

9. Short duration pulse test used to minimize self-heating effect.

10. Guaranteed by design. Not subject to product testing.







DMPH4013SK3Q Document number: DS40120 Rev. 4 - 2



0.03

0.025

0.02

0.01

0.005

0

30

25

20

15

10

5

0

10

9

8

7

5

1

V_{GS} (V)

I_s, source current (A)

g 0.015

R_{DS(ON)}, DRAIN-SOURCE ON-RESISTANCE

DMPH4013SK3Q

C_{iss}

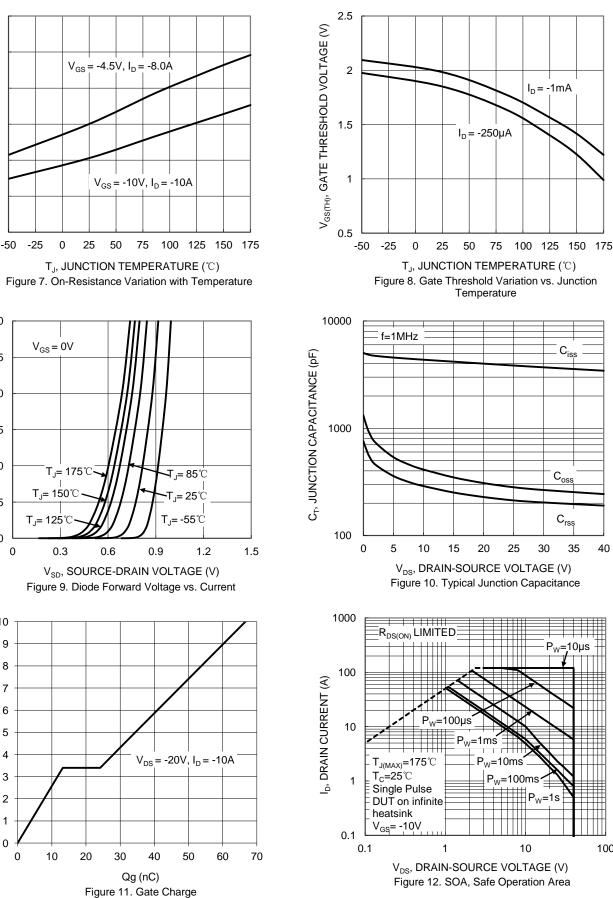
C_{oss}

C_{rss}

35

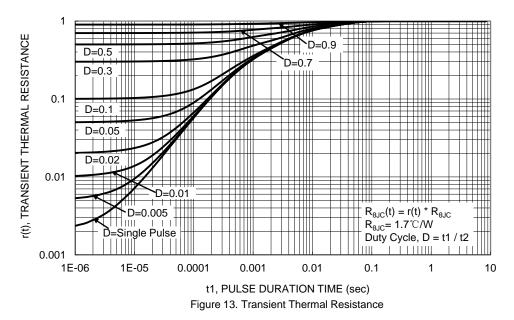
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DMPH4013SK3Q Document number: DS40120 Rev. 4 - 2 100

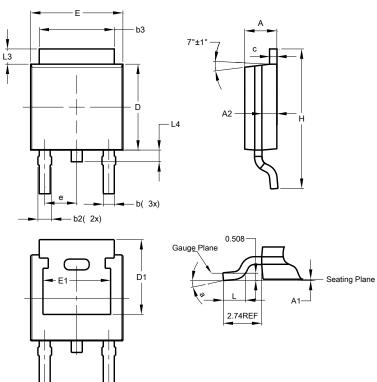






Package Outline Dimensions

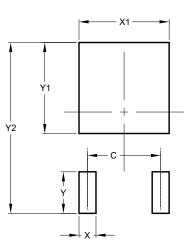
Please see http://www.diodes.com/package-outlines.html for the latest version.



	TO252 (DPAK)						
Dim	Min	Max	Тур				
Α	2.19	2.39	2.29				
A1	0.00	0.13	0.08				
A2	0.97	1.17	1.07				
b	0.64	0.88	0.783				
b2	0.76	1.14	0.95				
b3	5.21	5.46	5.33				
С	0.45	0.58	0.531				
D	6.00	6.20	6.10				
D1	5.21	-	-				
е	-	-	2.286				
Ε	6.45	6.70	6.58				
E1	4.32	-	-				
Н	9.40	10.41	9.91				
L	1.40	1.78	1.59				
L3	0.88	1.27	1.08				
L4	0.64	1.02	0.83				
а	0°	10°	-				
All	All Dimensions in mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



TO252 (
I UZJZ I	DEAN

Dimensions	Value (in mm)
С	4.572
Х	1.060
X1	5.632
Y	2.600
Y1	5.700
Y2	10.700

TO252 (DPAK)



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